



Integrated Device Technology, Inc.

CMOS STATIC RAM 256K (32K x 8-BIT) IN PE PACKAGES

IDT71256SA

FEATURES:

- 32K x 8 CMOS static RAM
- Equal access and cycle times
 - Commercial: 15/20/25/35/45/70ns
- One Chip Select plus one Output Enable pin
- Bidirectional data inputs and outputs directly TTL-compatible
- Low power consumption via chip deselect
- Available in 28-pin 330 mil Plastic SOIC.

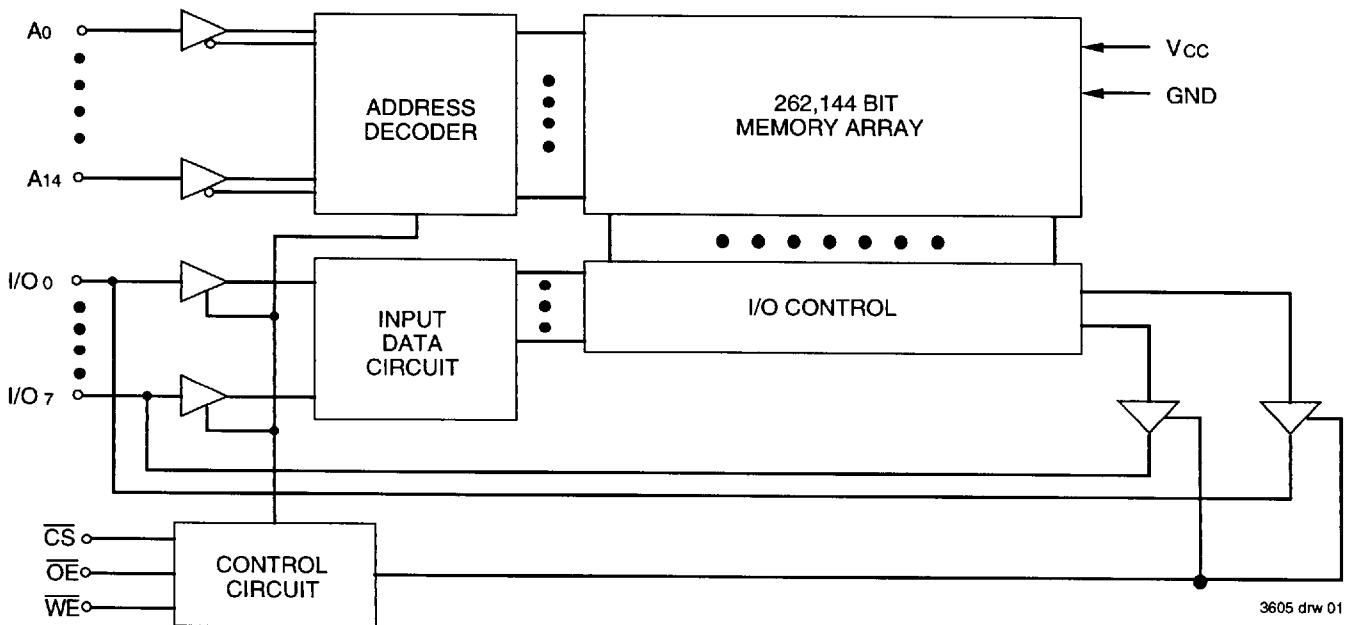
DESCRIPTION:

The IDT71256SA is a 262,144-bit Static RAM organized as 32K x 8. It is fabricated using IDT's high-performance, high-reliability CMOS technology. This state-of-the-art technology, combined with innovative circuit design techniques, provides a cost-effective solution for your memory needs.

All bidirectional inputs and outputs of the IDT71256SA are TTL-compatible and operation is from a single 5V supply. Fully static asynchronous circuitry is used, requiring no clocks or refresh for operation.

The IDT71256SA is packaged in a 28-pin 330 mil Plastic SOIC.

FUNCTIONAL BLOCK DIAGRAM



3605 drw 01

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COMMERCIAL TEMPERATURE RANGE

JULY 1996

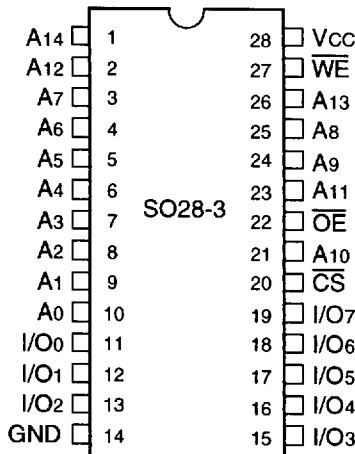
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1-1

PIN CONFIGURATIONS



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**SOIC
TOP VIEW**

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Com'l.	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +7.0	V
TA	Operating Temperature	0 to +70	°C
TBIAS	Temperature Under Bias	-55 to +125	°C
TSTG	Storage Temperature	-55 to +125	°C
PT	Power Dissipation	1.0	W
IOUT	DC Output Current	50	mA

NOTES:

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- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- VTERM must not exceed VCC + 0.5V.

RECOMMENDED DC OPERATING CONDITIONS

Symbol	Parameter	Min.	Typ.	Max.	Unit
VCC	Supply Voltage	4.5	5.0	5.5	V
GND	Supply Voltage	0	0	0	V
VIH	Input High Voltage	2.2	—	VCC+0.5	V
VIL	Input Low Voltage	-0.5 ⁽¹⁾	—	0.8	V

NOTE:

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- VIL (min.) = -1.5V for pulse width less than 10ns, once per cycle.

CAPACITANCE

(TA = +25°C, f = 1.0MHz, SOJ package)

Symbol	Parameter ⁽¹⁾	Conditions	Max.	Unit
CIN	Input Capacitance	VIN = 3dV	11	pF
CIO	I/O Capacitance	VOU = 3dV	11	pF

NOTE:

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- This parameter is guaranteed by device characterization, but not production tested.

TRUTH TABLE^(1,2)

CS	OE	WE	I/O	Function
L	L	H	DATAOUT	Read Data
L	X	L	DATAIN	Write Data
L	H	H	High-Z	Outputs Disabled
H	X	X	High-Z	Deselected — Standby (Ise)
VHC ⁽³⁾	X	X	High-Z	Deselected — Standby (Isb1)

NOTES:

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- H = VIH, L = VIL, x = Don't care.
- VLC = 0.2V, VHC = VCC - 0.2V.
- Other inputs ≥VHC or ≤VLC.

DC ELECTRICAL CHARACTERISTICS

VCC = 5.0V ± 10%

Symbol	Parameter	Test Condition	IDT71256SA		Unit
			Min.	Max.	
II _L	Input Leakage Current	VCC = Max., VIN = GND to VCC	—	5	μA
II _O	Output Leakage Current	VCC = Max., CS = VIH, VOUT = GND to VCC	—	5	μA
VOL	Output Low Voltage	IoL = 8mA, VCC = Min.	—	0.4	V
VOH	Output High Voltage	IoH = -4mA, VCC = Min.	2.4	—	V

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DC ELECTRICAL CHARACTERISTICS⁽¹⁾

($V_{CC} = 5.0V \pm 10\%$, $V_{LC} = 0.2V$, $V_{HC} = V_{CC} - 0.2V$)

Symbol	Parameter	71256SA15	71256SA20	71256SA25	Unit
I _{CC}	Dynamic Operating Current $\overline{CS} \leq V_{IL}$, Outputs Open, $V_{CC} = \text{Max.}$, $f = f_{MAX}^{(2)}$	150	145	145	mA
I _{SB}	Standby Power Supply Current (TTL Level) $\overline{CS} \geq V_{IH}$, Outputs Open, $V_{CC} = \text{Max.}$, $f = f_{MAX}^{(2)}$	40	40	40	mA
I _{SB1}	Standby Power Supply Current (CMOS Level) $\overline{CS} \geq V_{HC}$, Outputs Open, $V_{CC} = \text{Max.}$, $f = 0^{(2)}$ $V_{IN} \leq V_{LC}$ or $V_{IN} \geq V_{HC}$	15	15	15	mA

DC ELECTRICAL CHARACTERISTICS (CONTINUED)⁽¹⁾

($V_{CC} = 5.0V \pm 10\%$, $V_{LC} = 0.2V$, $V_{HC} = V_{CC} - 0.2V$)

Symbol	Parameter	71256SA35	71256SA45	71256SA70	Unit
I _{CC}	Dynamic Operating Current $\overline{CS} \leq V_{IL}$, Outputs Open, $V_{CC} = \text{Max.}$, $f = f_{MAX}^{(2)}$	140	135	130	mA
I _{SB}	Standby Power Supply Current (TTL Level) $\overline{CS} \geq V_{IH}$, Outputs Open, $V_{CC} = \text{Max.}$, $f = f_{MAX}^{(2)}$	30	30	20	mA
I _{SB1}	Standby Power Supply Current (CMOS Level) $\overline{CS} \geq V_{HC}$, Outputs Open, $V_{CC} = \text{Max.}$, $f = 0^{(2)}$ $V_{IN} \leq V_{LC}$ or $V_{IN} \geq V_{HC}$	15	15	15	mA

NOTES:

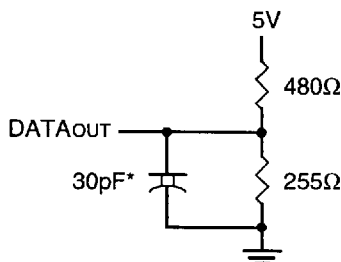
- All values are maximum guaranteed values.
- $f_{MAX} = 1/t_{RC}$ (all address inputs are cycling at f_{MAX}); $f = 0$ means no address input lines are changing.

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AC TEST CONDITIONS

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	3ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	See Figures 1 and 2

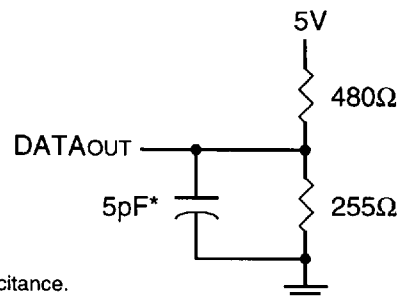
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*Including jig and scope capacitance.

Figure 1. AC Test Load



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Figure 2. AC Test Load
(for t_{CLZ}, t_{OLZ}, t_{CHZ}, t_{OHZ}, t_{OW}, and t_{WHZ})

AC ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0V \pm 10\%$)

Symbol	Parameter	71256SA15		71256SA20		71256SA25		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
Read Cycle								
t _{RC}	Read Cycle Time	15	—	20	—	25	—	ns
t _{AA}	Address Access Time	—	15	—	20	—	25	ns
t _{ACS}	Chip Select Access Time	—	15	—	20	—	25	ns
t _{CLZ} ⁽¹⁾	Chip Select to Output in Low-Z	4	—	4	—	4	—	ns
t _{CHZ} ⁽¹⁾	Chip Deselect to Output in High-Z	0	7	0	10	0	11	ns
t _{OE}	Output Enable to Output Valid	—	7	—	10	—	11	ns
t _{OLZ} ⁽¹⁾	Output Enable to Output in Low-Z	0	—	0	—	0	—	ns
t _{OHZ} ⁽¹⁾	Output Disable to Output in High-Z	0	6	0	8	0	10	ns
t _{OH}	Output Hold from Address Change	3	—	3	—	3	—	ns
t _{PU} ⁽¹⁾	Chip Select to Power Up Time	0	—	0	—	0	—	ns
t _{PD} ⁽¹⁾	Chip Deselect to Power Down Time	—	15	—	20	—	25	ns
Write Cycle								
t _{WC}	Write Cycle Time	15	—	20	—	25	—	ns
t _{AW}	Address Valid to End of Write	10	—	15	—	20	—	ns
t _{CW}	Chip Select to End of Write	10	—	15	—	20	—	ns
t _{AS}	Address Set-up Time	0	—	0	—	0	—	ns
t _{WP}	Write Pulse Width	10	—	15	—	20	—	ns
t _{WR}	Write Recovery Time	0	—	0	—	0	—	ns
t _{DW}	Data Valid to End of Write	7	—	11	—	13	—	ns
t _{DH}	Data Hold Time	0	—	0	—	0	—	ns
t _{OW} ⁽¹⁾	Output Active from End of Write	4	—	4	—	4	—	ns
t _{WHZ} ⁽¹⁾	Write Enable to Output in High-Z	0	6	0	10	0	11	ns

NOTE:

1. This parameter is guaranteed with the AC Load (Figure 2) by device characterization, but is not production tested.

3605 tbl 08

AC ELECTRICAL CHARACTERISTICS (CONTINUED) ($V_{CC} = 5.0V \pm 10\%$)

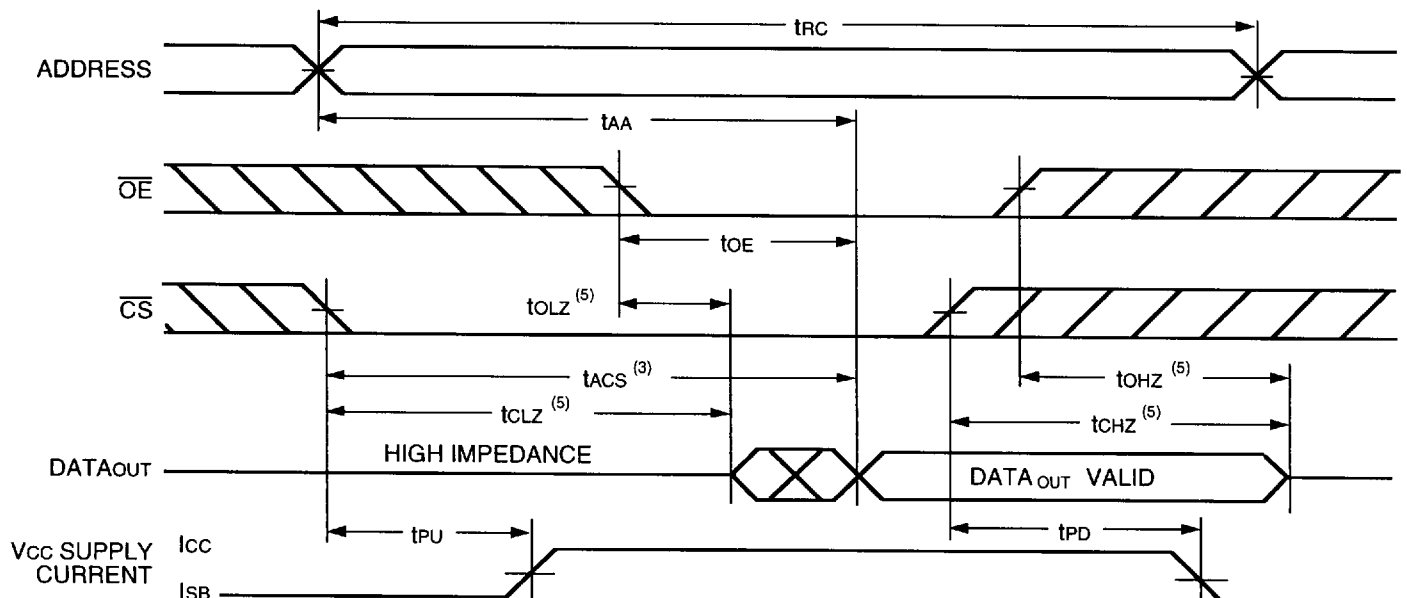
Symbol	Parameter	71256SA35		71256SA45		71256SA70		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
Read Cycle								
t _{RC}	Read Cycle Time	35	—	45	—	70	—	ns
t _{AA}	Address Access Time	—	35	—	45	—	70	ns
t _{ACS}	Chip Select Access Time	—	35	—	45	—	70	ns
t _{CLZ} ⁽¹⁾	Chip Select to Output in Low-Z	4	—	4	—	4	—	ns
t _{CHZ} ⁽¹⁾	Chip Deselect to Output in High-Z	0	11	0	11	0	11	ns
t _{OE}	Output Enable to Output Valid	—	11	—	11	—	11	ns
t _{OLZ} ⁽¹⁾	Output Enable to Output in Low-Z	0	—	0	—	0	—	ns
t _{OHZ} ⁽¹⁾	Output Disable to Output in High-Z	0	10	0	10	0	10	ns
t _{OH}	Output Hold from Address Change	3	—	3	—	3	—	ns
t _{PU} ⁽¹⁾	Chip Select to Power Up Time	0	—	0	—	0	—	ns
t _{PD} ⁽¹⁾	Chip Deselect to Power Down Time	—	25	—	25	—	25	ns
Write Cycle								
t _{WC}	Write Cycle Time	35	—	45	—	70	—	ns
t _{AW}	Address Valid to End of Write	20	—	20	—	20	—	ns
t _{CW}	Chip Select to End of Write	20	—	20	—	20	—	ns
t _{AS}	Address Set-up Time	0	—	0	—	0	—	ns
t _{WP}	Write Pulse Width	20	—	20	—	20	—	ns
t _{WR}	Write Recovery Time	0	—	0	—	0	—	ns
t _{DW}	Data Valid to End of Write	13	—	13	—	13	—	ns
t _{DH}	Data Hold Time	0	—	0	—	0	—	ns
t _{OW} ⁽¹⁾	Output Active from End of Write	4	—	4	—	4	—	ns
t _{WHZ} ⁽¹⁾	Write Enable to Output in High-Z	0	11	0	11	0	11	ns

NOTE:

1. This parameter is guaranteed with the AC Load (Figure 2) by device characterization, but is not production tested.

3605 tbl 08

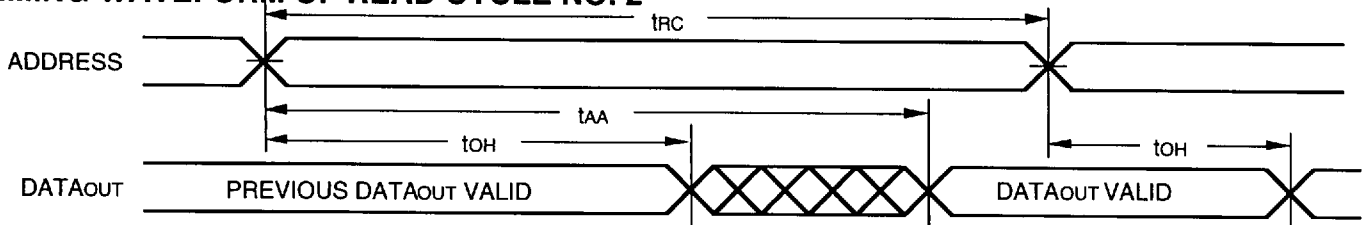
TIMING WAVEFORM OF READ CYCLE NO. 1⁽¹⁾



3605 drw 05

1-5

TIMING WAVEFORM OF READ CYCLE NO. 2^(1,2,4)

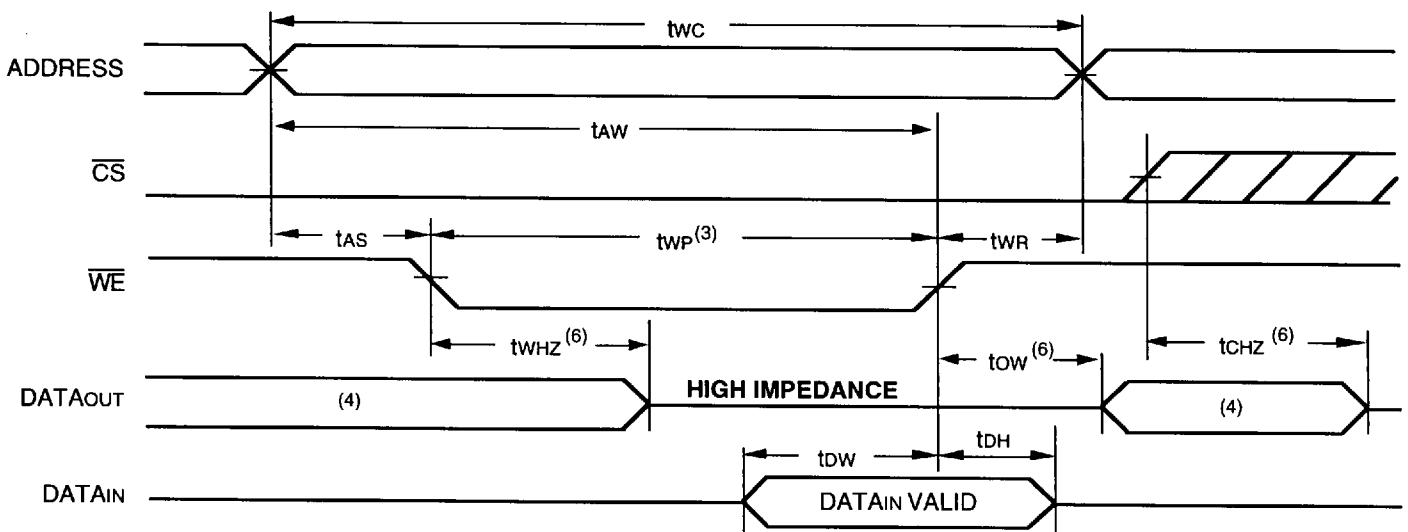


NOTES:

1. \overline{WE} is HIGH for Read Cycle.
2. Device is continuously selected, \overline{CS} is LOW.
3. Address must be valid prior to or coincident with the later of \overline{CS} transition LOW; otherwise t_{AA} is the limiting parameter.
4. \overline{OE} is LOW.
5. Transition is measured $\pm 200\text{mV}$ from steady state.

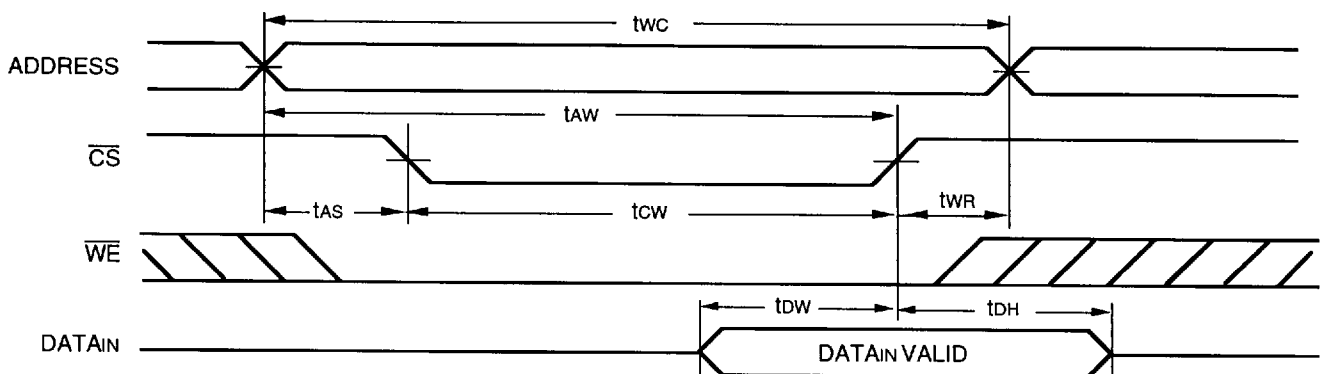
3605 drw 06

TIMING WAVEFORM OF WRITE CYCLE NO.1 (\overline{WE} CONTROLLED TIMING)^(1,2,3,5)



3605 drw 07

TIMING WAVEFORM OF WRITE CYCLE NO.2 (\overline{CS} CONTROLLED TIMING)^(1,2,5)

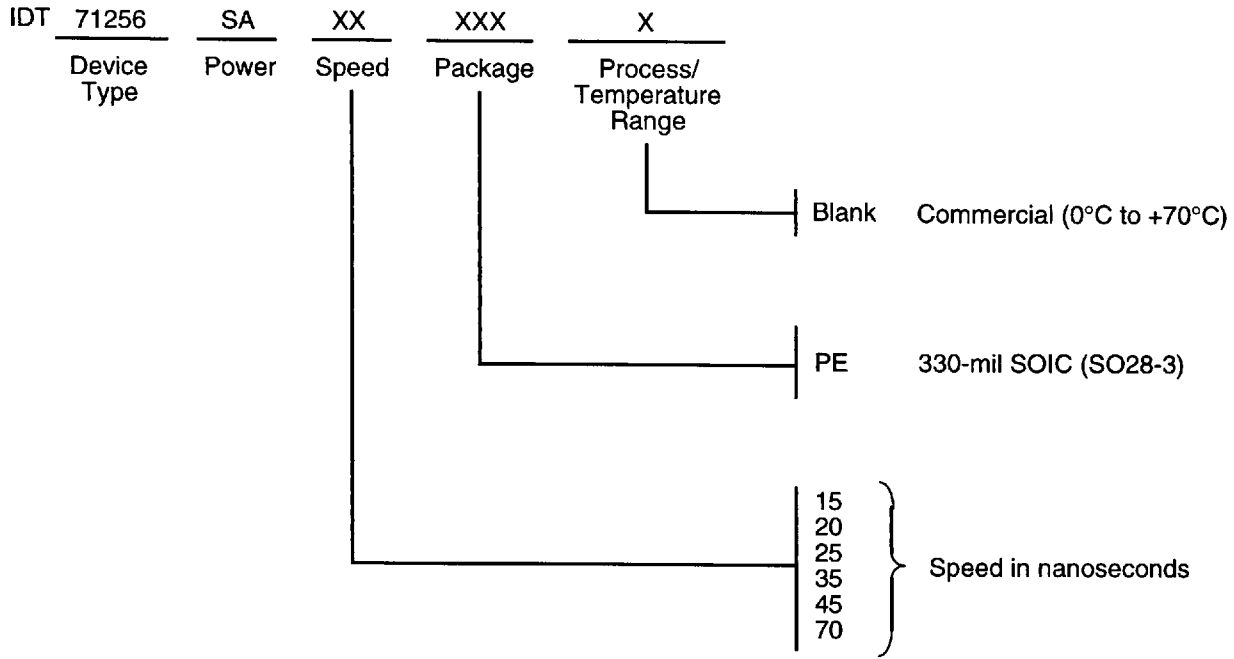


NOTES:

1. \overline{WE} or \overline{CS} must be HIGH during all address transitions.
2. A write occurs during the overlap of a LOW \overline{CS} and a LOW \overline{WE} .
3. \overline{OE} is continuously HIGH. If during a \overline{WE} controlled write cycle \overline{OE} is LOW, t_{WP} must be greater than or equal to $t_{WHZ} + t_{DW}$ to allow the I/O drivers to turn off and data to be placed on the bus for the required t_{DW} . If \overline{OE} is HIGH during a \overline{WE} controlled write cycle, this requirement does not apply and the minimum write pulse is as short as the specified t_{WP} .
4. During this period, I/O pins are in the output state, and input signals must not be applied.
5. If the \overline{CS} LOW transition occurs simultaneously with or after the \overline{WE} LOW transition, the outputs remain in a high-impedance state.
6. Transition is measured $\pm 200\text{mV}$ from steady state.

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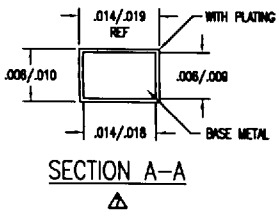
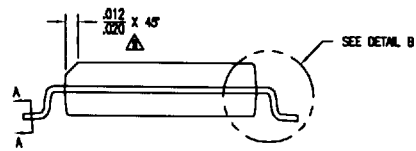
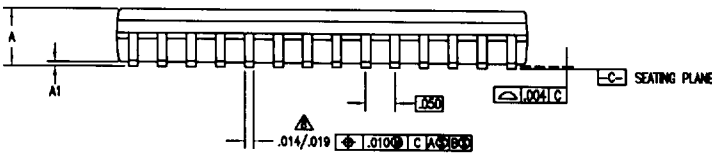
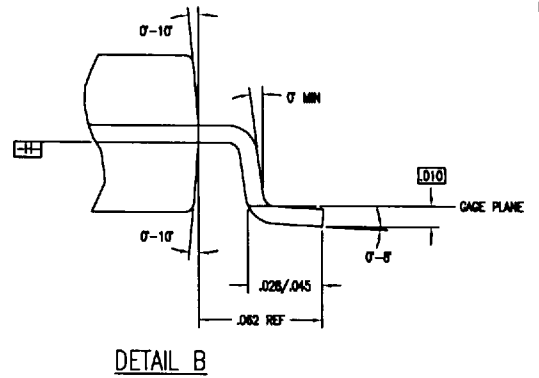
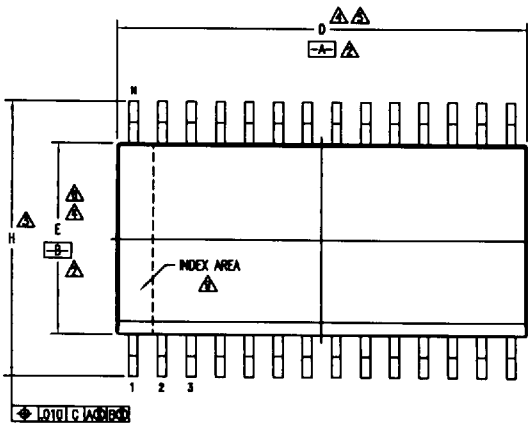
ORDERING INFORMATION



3605 drw 09

PACKAGE DIAGRAM OUTLINES
SOIC (Continued)

REVISIONS				
DCH	REV	DESCRIPTION	DATE	APPROVED
27842	03	REDRAW TO JEDEC FORMAT	03/15/98	



TOLERANCES UNLESS SPECIFIED		INTEGRATED DEVICE TECHNOLOGY, INC.	
DECIMAL	ANGULAR	2870 Shafter Way, Santa Clara, CA 95054	PHONE: (408) 737-8116
±	±	FAX: (408) 482-8874	TRE: 910-338-2070
APPROVALS	DATE	TITLE PE PACKAGE OUTLINE	
DRW: AA	07/19/98	.330" BODY WIDTH SOIC	
CHECKED		.050" PITCH	
		SIZE C	DRAWING No. PSC-4016
			REV 03
DO NOT SCALE DRAWING			

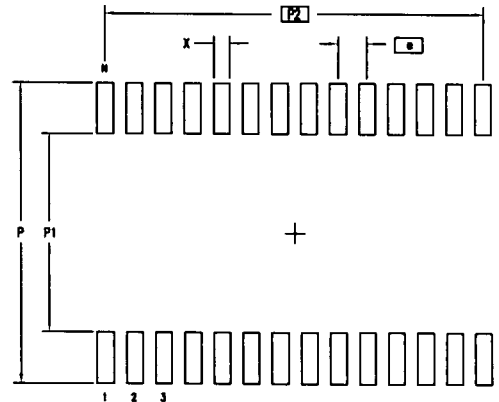
PACKAGE DIAGRAM OUTLINES

SOIC (Continued)

KEYWORD				
DCH	REV	DESCRIPTION	DATE	APPROVED
27842	03	REDRAW TO JEDEC FORMAT	03/15/95	

SYMBOL	DWC #			S028-3			NOTE
	JEDEC VARIATION						
	AD						
	MIN	NOM	MAX				
A	.110	.115	.120				
A1	.005	.010	.014				
D	.718	.723	.728	4,5			
E	.340	.345	.350	4,6			
H	.462	.470	.478	3			
N	28						

LAND PATTERN DIMENSIONS



	MIN	MAX
P	.512	.520
P1	.336	.344
P2	.650 BSC	
X	.024	.032
e	.050 BSC	
N	28	

NOTES:

- ALL DIMENSIONING AND TOLERANCING CONFORM TO ANSI Y14.5M-1982
- DATUMS **-A-** AND **-B-** TO BE DETERMINED AT DATUM PLANE **-H-**
- DIMENSION H TO BE DETERMINED AT SEATING PLANE **-C-**
- DIMENSIONS D AND E ARE TO BE DETERMINED AT DATUM PLANE **-H-**
- DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS AND GATE BURRS SHALL NOT EXCEED .006 PER SIDE
- DIMENSION E DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS. INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 PER SIDE
- THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND .010 FROM LEAD TIP
- LEAD WIDTH DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION IS .004 IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT
- THE CHAMFER ON THE PACKAGE BODY IS OPTIONAL. IF IT IS NOT PRESENT, A VISUAL INDEX FEATURE MUST BE LOCATED WITHIN THE ZONE INDICATED
- ALL DIMENSIONS ARE IN INCHES
- THIS OUTLINE CONFORMS TO JEDEC PUBLICATION 95 REGISTRATION MO-059, VARIATION AD. EXCEPTIONS: JEDEC MAXIMUM INTERLEAD FLASH OR PROTRUSIONS IS .006

TOLERANCES UNLESS SPECIFIED		INTEGRATED DEVICE TECHNOLOGY, INC.	
DECIMAL	ANGULAR	2878 Shafter Way, Santa Clara, CA 95054	
±	±	PHONE (408) 727-6116	
		FAX (408) 498-8074 TWR 910-338-8070	
APPROVALS	DATE	TITLE PE PACKAGE OUTLINE	
DRAWN JLD	02/16/95	.330" BODY WIDTH SOIC	
CHECKED		.050" PITCH	
		SIZE C	DRAWING No. PSC-4016
			REV 03
DO NOT SCALE DRAWING			